



# N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
60	0.025 at V <sub>GS</sub> = 10 V	8.7		
	0.036 at V <sub>GS</sub> = 4.5 V	7.3		

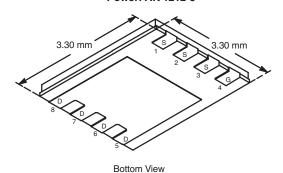
#### **FEATURES**

- TrenchFET® Power MOSFET
- New Low Thermal Resistance
- PowerPAK® 1212-8 Package with Low 1.07-mm Profile
- PWM Optimized



COMPLIANT

#### PowerPAK 1212-8

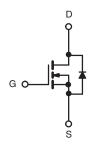


Ordering Information: Si7414DN-T1

Si7414DN-T1-E3 (Lead (Pb)-free)

#### **APPLICATIONS**

- Primary Side Switch
- Synchronous Rectifier
- Motor Drives



N-Channel MOSFET

ABSOLUTE MAXIMUM RATING	<b>S</b> $T_A = 25  ^{\circ}C$	unless otherwis	se noted		
Parameter		Symbol	10 secs	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	60		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	8.7	5.6	
	T <sub>A</sub> = 70 °C		7.0	4.4	
Pulsed Drain Current		I <sub>DM</sub>	30		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	3.2	1.3	
Single Avalanche Current	1 01 mll	I <sub>AS</sub>	19 18		
Single Avalanche Energy (Duty Cycle 1 %)	L = 0.1 mH	E <sub>AS</sub>			mJ
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.8	1.5	W
	T <sub>A</sub> = 70 °C		2.0	0.8	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations <sup>b,c</sup>			260		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 sec	- R <sub>thJA</sub>	26	33	
	Steady State		65	81	°C/W
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	1.9	2.4	1

a. Surface Mounted on 1" x 1" FR4 Board.

a. Surface Mothled of 17 x 1 PA4 Board.

b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

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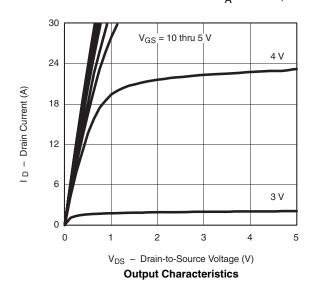
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static			1		l.		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V			1	1 5 μΑ	
		V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			5		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
Drain-Source On-State Resistance <sup>a</sup>	_	$V_{GS} = 10 \text{ V}, I_D = 8.7 \text{ A}$	0.021 0.02		0.025		
	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 7.3 \text{ A}$		0.030	0.036	Ω	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 8.7 \text{ A}$		18		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_S = 3.2 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V	
Dynamic <sup>b</sup>	1		1	-	I .		
Total Gate Charge	Qg			16	25		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 8.7 \text{ A}$		2.7		nC	
Gate-Drain Charge	Q <sub>gd</sub>			4.4		1	
Gate Resistance	$R_g$			1.0		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			15	25		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 30 $\Omega$		12	20		
Turn-Off DelayTime	t <sub>d(off)</sub>	$I_D \cong$ 1 A, $V_{GEN}$ = 10 V, $R_g$ = 6 $\Omega$		30	50	ns	
Fall Time	t <sub>f</sub>			12	20	1	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 3.2 A, di/dt = 100 A/μs		45	90		

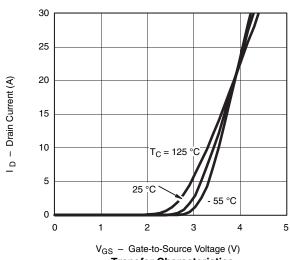
#### Notes

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted



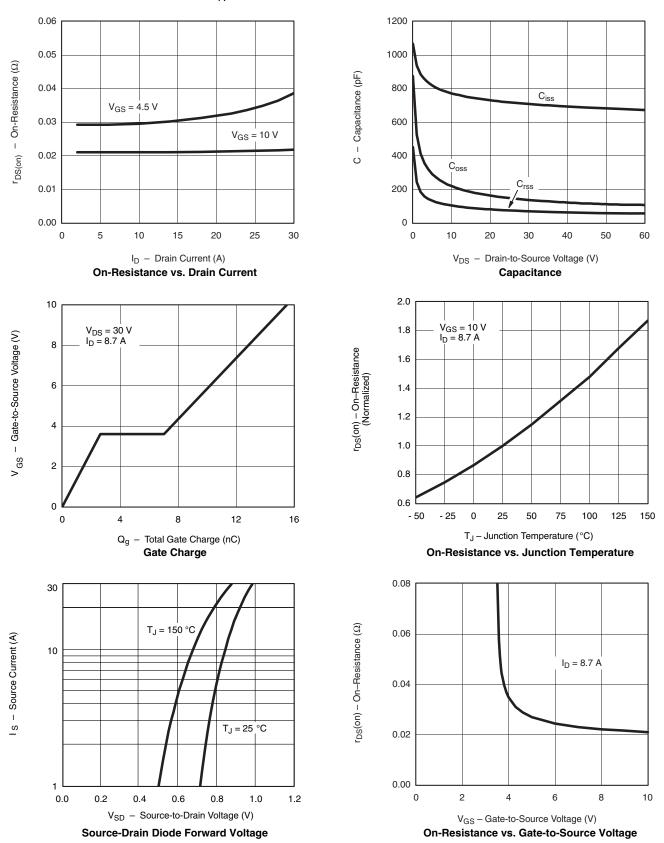








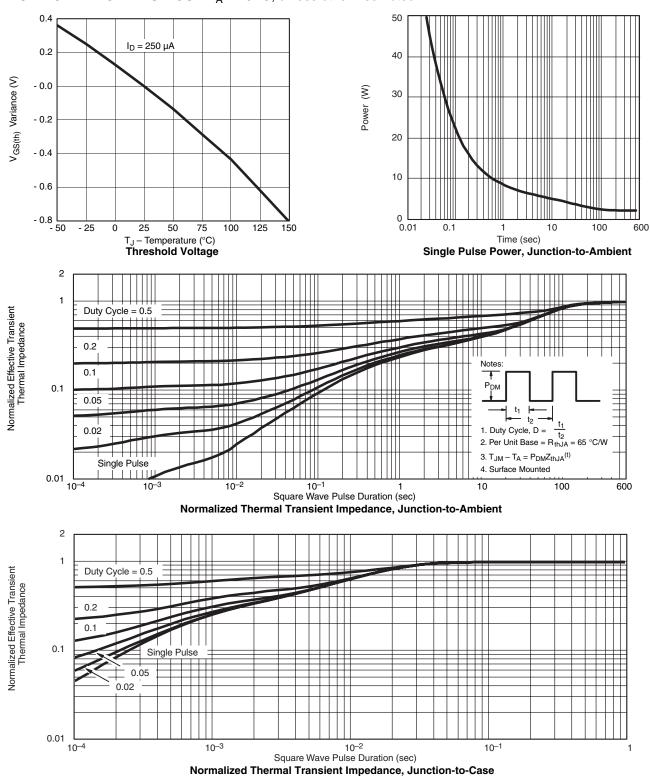
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